

4A, 400V - 600V Hyperfast Diodes

The RHRD440, RHRD460, RHRD440S and RHRD460S are hyperfast diodes with soft recovery characteristics ($t_{rr} < 30ns$). They have half the recovery time of ultrafast diodes and are of silicon nitride passivated ion-implanted epitaxial planar construction.

These devices are intended for use as freewheeling/clamping diodes and rectifiers in a variety of switching power supplies and other power switching applications. Their low stored charge and hyperfast soft recovery minimize ringing and electrical noise in many power switching circuits, reducing power loss in the switching transistors.

Formerly developmental type TA49055.

Ordering Information

PART NUMBER	PACKAGE	BRAND
RHRD440	TO-251	RHR440
RHRD460	TO-251	RHR460
RHRD440S	TO-252	RHR440
RHRD460S	TO-252	RHR460

NOTE: When ordering, use the entire part number. Add the suffix 9A to obtain the TO-252AA variant in the tape and reel, i.e., RHRD460S9A.

Symbol



勝特力材料 886-3-5753170
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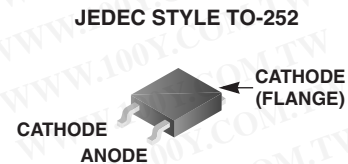
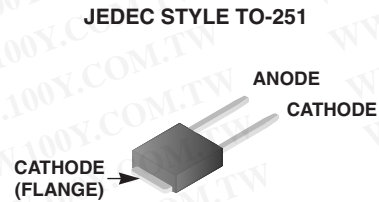
Features

- Hyperfast with Soft Recovery <30ns
- Operating Temperature 175°C
- Reverse Voltage Up to 600V
- Avalanche Energy Rated
- Planar Construction

Applications

- Switching Power Supplies
- Power Switching Circuits
- General Purpose

Packaging



Absolute Maximum Ratings $T_C = 25^\circ C$, Unless Otherwise Specified

	RHRD440, RHRD440S	RHRD460, RHRD460S	UNITS
Peak Repetitive Reverse Voltage	400	600	V
Working Peak Reverse Voltage	400	600	V
DC Blocking Voltage	400	600	V
Average Rectified Forward Current ($T_C = 157^\circ C$)	4	4	A
Repetitive Peak Surge Current (Square Wave, 20kHz)	8	8	A
Nonrepetitive Peak Surge Current (Halfwave, 1 Phase, 60Hz)	40	40	A
Maximum Power Dissipation	50	50	W
Avalanche Energy (See Figures 10 and 11)	10	10	mJ
Operating and Storage Temperature	-65 to 175	-65 to 175	°C
Maximum Lead Temperature for Soldering (Leads at 0.063 in. (1.6mm) from case for 10s)	300	300	°C
Package Body for 10s, see Tech Brief 334.	260	260	°C

RHRD440, RHRD460, RHRD440S, RHRD460S

Electrical Specifications $T_C = 25^\circ\text{C}$, Unless Otherwise Specified

SYMBOL	TEST CONDITION	RHRD440, RHRD440S			RHRD460, RHRD460S			UNITS
		MIN	TYP	MAX	MIN	TYP	MAX	
V_F	$I_F = 4\text{A}$	-	-	2.1	-	-	2.1	V
	$I_F = 4\text{A}, T_C = 150^\circ\text{C}$	-	-	1.7	-	-	1.7	V
I_R	$V_R = 400\text{V}$	-	-	100	-	-	-	μA
	$V_R = 600\text{V}$	-	-	-	-	-	100	μA
	$V_R = 400\text{V}, T_C = 150^\circ\text{C}$	-	-	500	-	-	-	μA
	$V_R = 600\text{V}, T_C = 150^\circ\text{C}$	-	-	-	-	-	500	μA
t_{rr}	$I_F = 1\text{A}, dI_F/dt = 200\text{A}/\mu\text{s}$	-	-	30	-	-	30	ns
	$I_F = 4\text{A}, dI_F/dt = 200\text{A}/\mu\text{s}$	-	-	35	-	-	35	ns
t_a	$I_F = 4\text{A}, dI_F/dt = 200\text{A}/\mu\text{s}$	-	16	-	-	16	-	ns
t_b	$I_F = 4\text{A}, dI_F/dt = 200\text{A}/\mu\text{s}$	-	7	-	-	7	-	ns
Q_{RR}	$I_F = 4\text{A}, dI_F/dt = 200\text{A}/\mu\text{s}$	-	45	-	-	45	-	nC
C_J	$V_R = 10\text{V}, I_F = 0\text{A}$	-	15	-	-	15	-	pF
$R_{\theta JC}$		-	-	3	-	-	3	$^\circ\text{C}/\text{W}$

DEFINITIONS

V_F = Instantaneous forward voltage (pw = 300 μs , D = 2%).

I_R = Instantaneous reverse current.

t_{rr} = Reverse recovery time (See Figure 9), summation of $t_a + t_b$.

t_a = Time to reach peak reverse current (See Figure 9).

t_b = Time from peak I_{RM} to projected zero crossing of I_{RM} based on a straight line from peak I_{RM} through 25% of I_{RM} (See Figure 9).

Q_{RR} = Reverse recovery charge.

C_J = Junction Capacitance.

$R_{\theta JC}$ = Thermal resistance junction to case.

pw = Pulse width.

D = Duty cycle.

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Typical Performance Curves

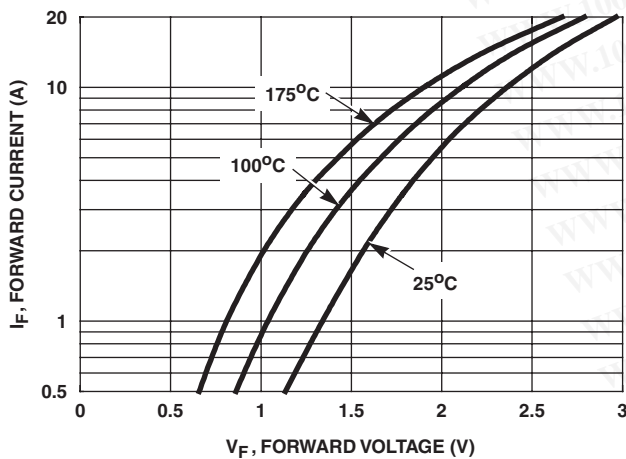


FIGURE 1. FORWARD CURRENT vs FORWARD VOLTAGE

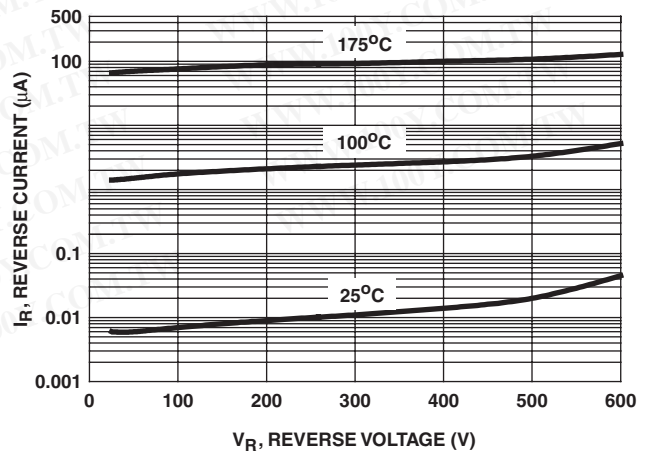


FIGURE 2. REVERSE CURRENT vs REVERSE VOLTAGE

Typical Performance Curves (Continued)

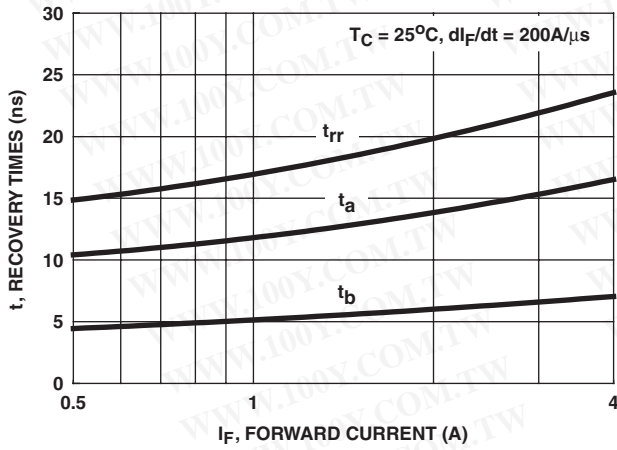


FIGURE 3. t_{rr} , t_a AND t_b CURVES vs FORWARD CURRENT

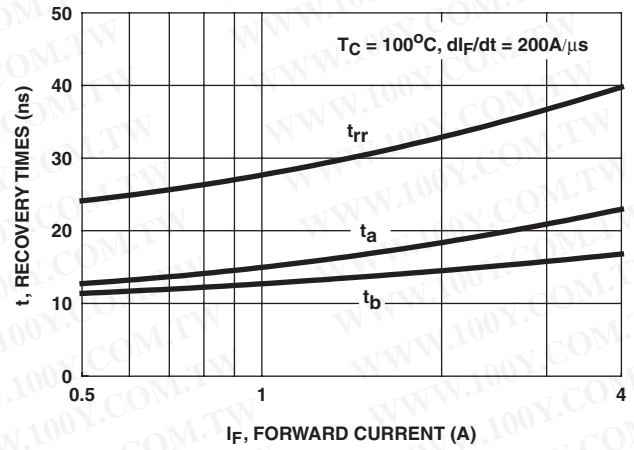


FIGURE 4. t_{rr} , t_a AND t_b CURVES vs FORWARD CURRENT

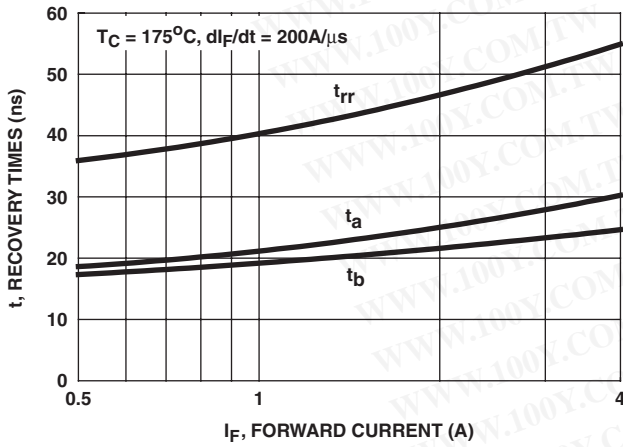


FIGURE 5. t_{rr} , t_a AND t_b CURVES vs FORWARD CURRENT

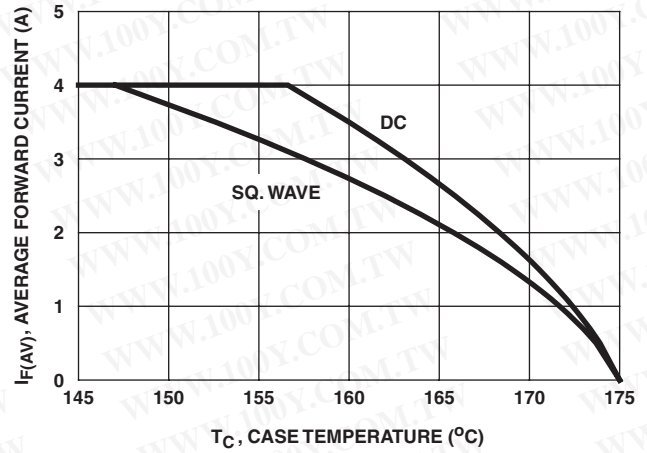


FIGURE 6. CURRENT DERATING CURVE

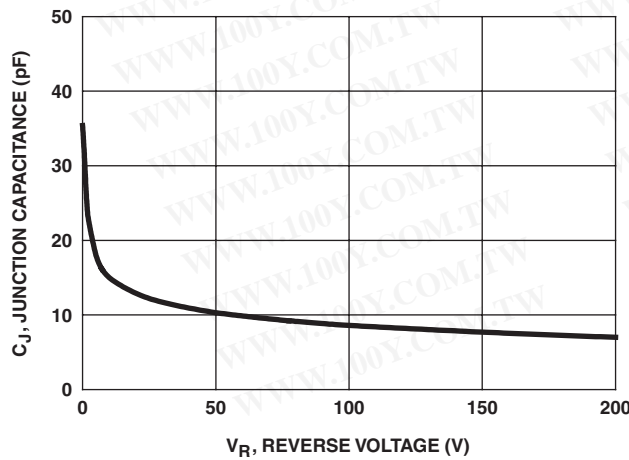


FIGURE 7. JUNCTION CAPACITANCE vs REVERSE VOLTAGE

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Test Circuits and Waveforms

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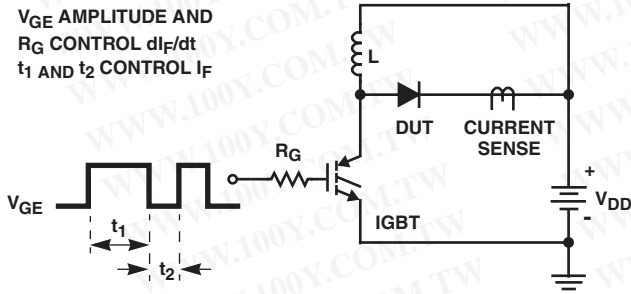


FIGURE 8. t_{rr} TEST CIRCUIT

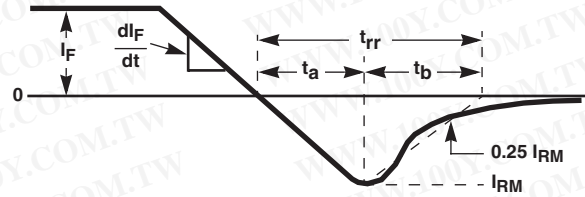


FIGURE 9. t_{rr} WAVEFORMS AND DEFINITIONS

$I_{MAX} = 1A$
 $L = 20mH$
 $R < 0.1\Omega$
 $E_{AVL} = 1/2LI^2 [V_{R(AVL)}/(V_{R(AVL)} - V_{DD})]$
 $Q_1 = IGBT (BV_{CES} > DUT V_{R(AVL)})$

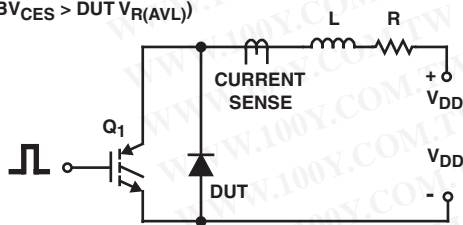


FIGURE 10. AVALANCHE ENERGY TEST CIRCUIT

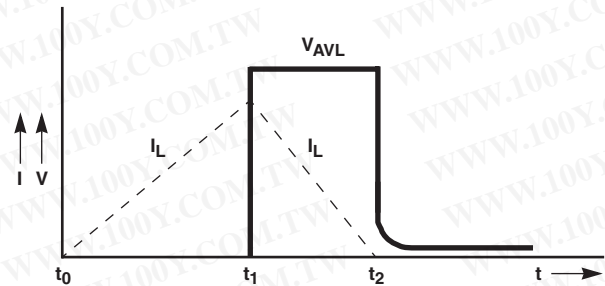


FIGURE 11. AVALANCHE CURRENT AND VOLTAGE WAVEFORMS

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